

CSD18537NQ5A 60V N 通道 NexFET™ 功率金属氧化物半导体场效应晶体管 (MOSFET)

1 特性

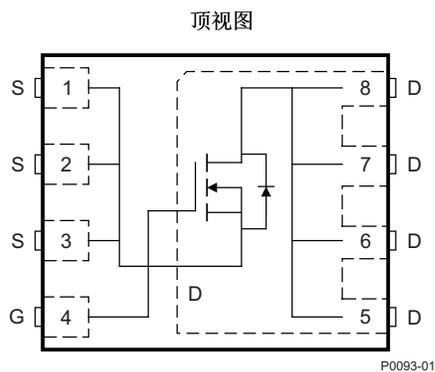
- 超低 Q_g 和 Q_{gd}
- 低热阻
- 雪崩级
- 无铅端子镀层
- 符合 RoHS 标准
- 无卤素
- 小外形尺寸无引线 (SON) 5mm x 6mm 塑料封装

2 应用范围

- 高侧同步降压转换器
- 电机控制

3 说明

这款 10mΩ, 60V, SON 5mm x 6mm NexFET™ 功率 MOSFET 被设计成最大限度地减少功率转换应用中的损耗。



产品概要

$T_A = 25^\circ\text{C}$		典型值		单位
V_{DS}	漏源电压	60		V
Q_g	栅极电荷总量 (10V)	14		nC
Q_{gd}	栅漏栅极电荷	2.3		nC
$R_{DS(on)}$	漏源导通电阻	$V_{GS} = 6V$	13	mΩ
		$V_{GS} = 10V$	10	mΩ
$V_{GS(th)}$	阈值电压	3		V

订购信息⁽¹⁾

器件	数量	介质	封装	出货
CSD18537NQ5A	2500	13 英寸卷带	SON 5mm x 6mm 塑料封装	卷带封装
CSD18537NQ5AT	250	7 英寸卷带		

(1) 要了解所有可用封装, 请见数据表末尾的可订购产品附录。

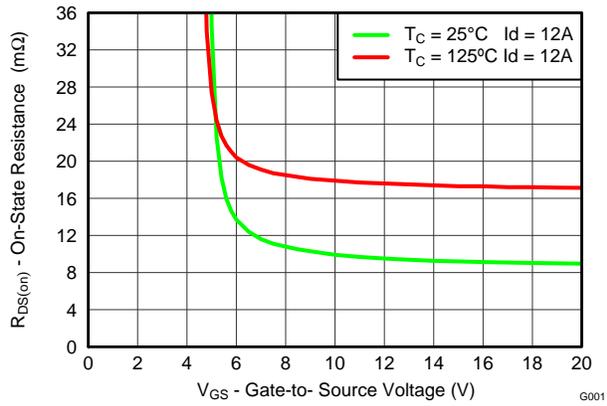
最大绝对额定值

$T_A = 25^\circ\text{C}$		值	单位
V_{DS}	漏源电压	60	V
V_{GS}	栅源电压	±20	V
I_D	持续漏极电流 (受封装限制)	50	A
	持续漏极电流 (受芯片限制), $T_C = 25^\circ\text{C}$ 时测得	54	
	持续漏极电流 ⁽¹⁾	11	
I_{DM}	脉冲漏极电流 ⁽²⁾	151	A
P_D	功率耗散 ⁽¹⁾	3.2	W
	功率耗散, $T_C = 25^\circ\text{C}$	75	
T_J, T_{stg}	运行结温和储存温度范围	-55 至 150	°C
E_{AS}	雪崩能量, 单脉冲 $I_D = 33A, L = 0.1mH, R_G = 25\Omega$	55	mJ

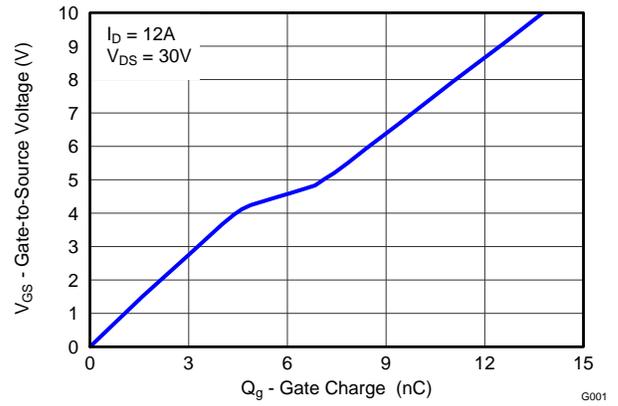
(1) $R_{\theta JA} = 40^\circ\text{C/W}$, 这是在一个厚度 0.06 英寸环氧树脂 (FR4) 印刷电路板 (PCB) 上的 1 英寸², 2 盎司的铜过渡垫片上测得的典型值

(2) 最大 $R_{\theta JC} = 2.1^\circ\text{C/W}$, 脉冲持续时间 $\leq 100\mu\text{s}$, 占空比 $\leq 1\%$

$R_{DS(on)}$ 与 V_{GS} 间的关系



栅极电荷



目录

1	特性	1	6	器件和文档支持	8
2	应用范围	1	6.1	Trademarks	8
3	说明	1	6.2	Electrostatic Discharge Caution	8
4	修订历史记录	3	6.3	术语表	8
5	Specifications	4	7	机械封装和可订购信息	9
5.1	Electrical Characteristics	4	7.1	Q5A 封装尺寸	10
5.2	Thermal Information	4	7.2	建议印刷电路板 (PCB) 布局	11
5.3	Typical MOSFET Characteristics	5	7.3	建议模板开口	12
			7.4	Q5A 卷带信息	12

4 修订历史记录

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision A (February 2014) to Revision B	Page
• 由于 $R_{\theta JC}$ 增大, 芯片电流限值降至 54A	1
• 添加了外壳温度保持在 25°C 时的最大功耗一行	1
• 更新了脉冲电流条件	1
• Increased the maximum $R_{\theta JC}$ to 2.1 °C/W	4
• Updated Figure 1 from a normalized $R_{\theta JA}$ curve to an $R_{\theta JC}$ curve	5
• Updated Figure 10 to show an improved SOA	6
• Updated Figure 12 to show a 50-A package current limit	6

Changes from Original (June 2013) to Revision A	Page
• 在标题中添加了部件号	1
• 已在说明中添加更多信息	1
• 已更新订购信息以包含小卷带信息	1
• 已从受封装限制的持续漏极电流中删除 $T_C = 25^\circ\text{C}$ 这一条件	1
• 脉冲电流限值增加为 151	1

5 Specifications

5.1 Electrical Characteristics

 (T_A = 25°C unless otherwise stated)

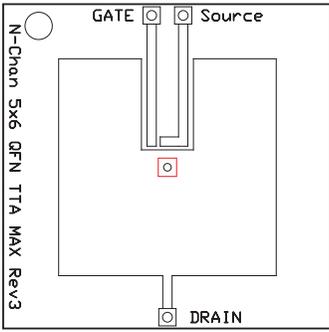
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC CHARACTERISTICS						
B _V DSS	Drain-to-Source Voltage	V _{GS} = 0 V, I _D = 250 μA	60			V
I _{DSS}	Drain-to-Source Leakage Current	V _{GS} = 0 V, V _{DS} = 48 V			1	μA
I _{GSS}	Gate-to-Source Leakage Current	V _{DS} = 0 V, V _{GS} = 20 V			100	nA
V _{GS(th)}	Gate-to-Source Threshold Voltage	V _{DS} = V _{GS} , I _D = 250 μA	2.6	3	3.5	V
R _{DS(on)}	Drain-to-Source On Resistance	V _{GS} = 6 V, I _D = 12 A		13	17	mΩ
		V _{GS} = 10 V, I _D = 12 A		10	13	mΩ
g _{fs}	Transconductance	V _{DS} = 30 V, I _D = 12 A		62		S
DYNAMIC CHARACTERISTICS						
C _{iss}	Input Capacitance	V _{GS} = 0 V, V _{DS} = 30 V, f = 1 MHz		1140	1480	pF
C _{oss}	Output Capacitance			136	177	pF
C _{rss}	Reverse Transfer Capacitance			4	5.2	pF
R _G	Series Gate Resistance			5.5	11	Ω
Q _g	Gate Charge Total (10 V)	V _{DS} = 30 V, I _D = 12 A		14	18	nC
Q _{gd}	Gate Charge Gate-to-Drain			2.3		nC
Q _{gs}	Gate Charge Gate-to-Source			4.7		nC
Q _{g(th)}	Gate Charge at V _{th}			3.3		nC
Q _{oss}	Output Charge	V _{DS} = 30 V, V _{GS} = 0 V		25		nC
t _{d(on)}	Turn On Delay Time	V _{DS} = 30 V, V _{GS} = 10 V, I _{DS} = 12 A, R _G = 0 Ω		5.8		ns
t _r	Rise Time			4		ns
t _{d(off)}	Turn Off Delay Time			14.4		ns
t _f	Fall Time			3.2		ns
DIODE CHARACTERISTICS						
V _{SD}	Diode Forward Voltage	I _{SD} = 12 A, V _{GS} = 0 V		0.8	1	V
Q _{rr}	Reverse Recovery Charge	V _{DS} = 30 V, I _F = 12 A, di/dt = 300 A/μs		54		nC
t _{rr}	Reverse Recovery Time			40		ns

5.2 Thermal Information

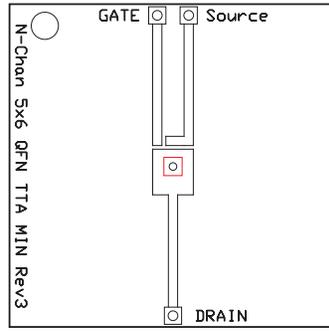
 (T_A = 25°C unless otherwise stated)

THERMAL METRIC		MIN	TYP	MAX	UNIT
R _{θJC}	Junction-to-Case Thermal Resistance ⁽¹⁾			2.1	°C/W
R _{θJA}	Junction-to-Ambient Thermal Resistance ⁽¹⁾⁽²⁾			50	

- (1) R_{θJC} is determined with the device mounted on a 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 1.5-inches × 1.5-inches (3.81-cm × 3.81-cm), 0.06-inch (1.52-mm) thick FR4 PCB. R_{θJC} is specified by design, whereas R_{θJA} is determined by the user's board design.
- (2) Device mounted on FR4 material with 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu.



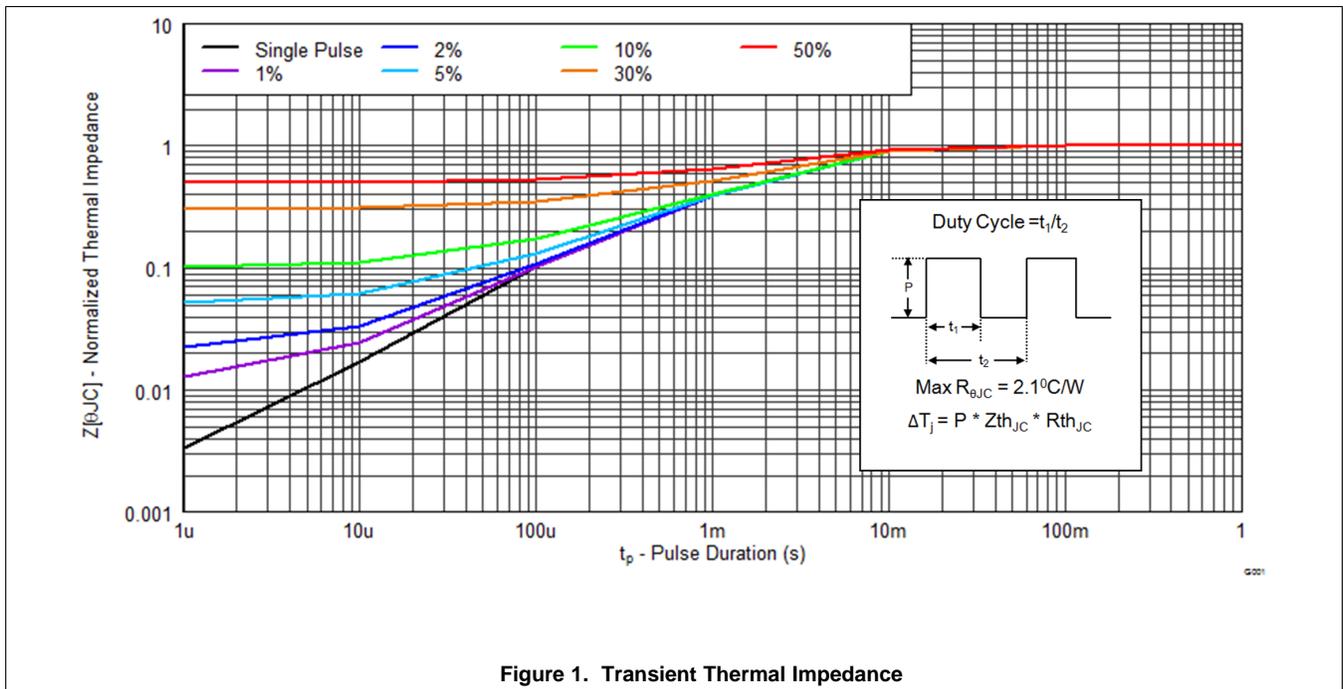
Max $R_{\theta JA} = 50^{\circ}\text{C/W}$
 when mounted on
 1 inch² (6.45 cm²) of
 2-oz. (0.071-mm thick)
 Cu.



Max $R_{\theta JA} = 125^{\circ}\text{C/W}$
 when mounted on a
 minimum pad area of
 2-oz. (0.071-mm thick)
 Cu.

5.3 Typical MOSFET Characteristics

($T_A = 25^{\circ}\text{C}$ unless otherwise stated)



Typical MOSFET Characteristics (continued)

($T_A = 25^\circ\text{C}$ unless otherwise stated)

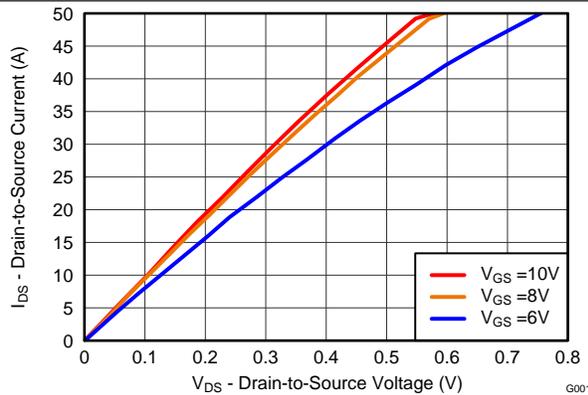


Figure 2. Saturation Characteristics

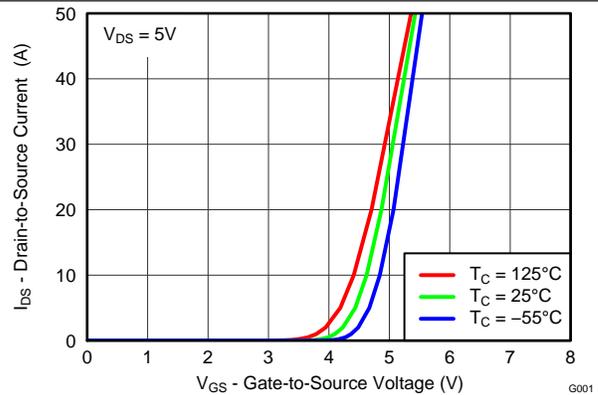


Figure 3. Transfer Characteristics

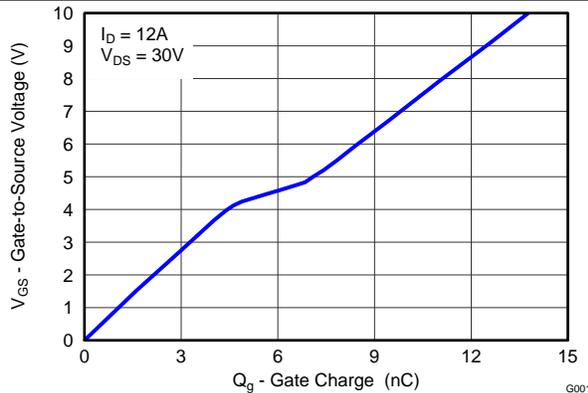


Figure 4. Gate Charge

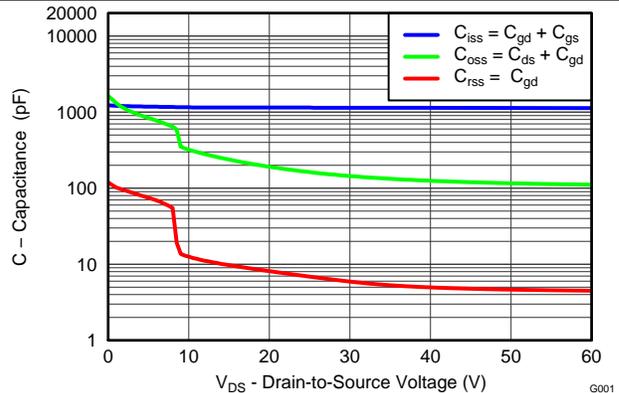


Figure 5. Capacitance

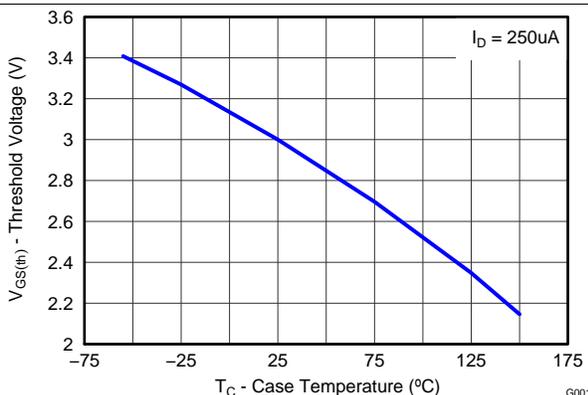


Figure 6. Threshold Voltage vs Temperature

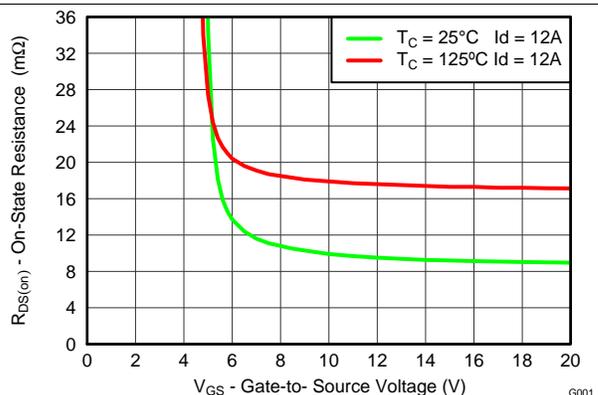


Figure 7. On-State Resistance vs Gate-to-Source Voltage

Typical MOSFET Characteristics (continued)

($T_A = 25^\circ\text{C}$ unless otherwise stated)

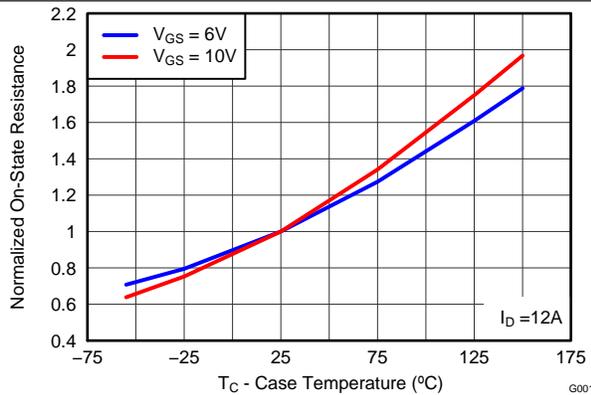


Figure 8. Normalized On-State Resistance vs Temperature

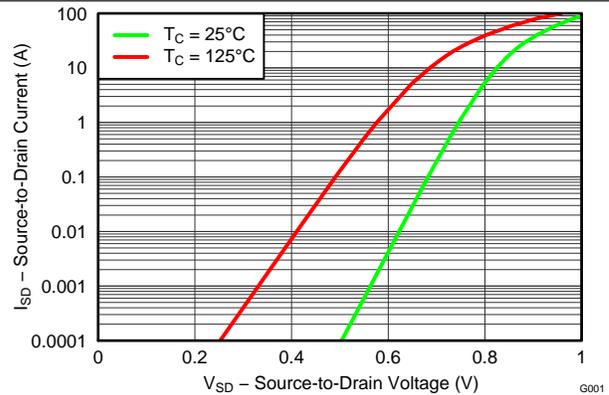


Figure 9. Typical Diode Forward Voltage

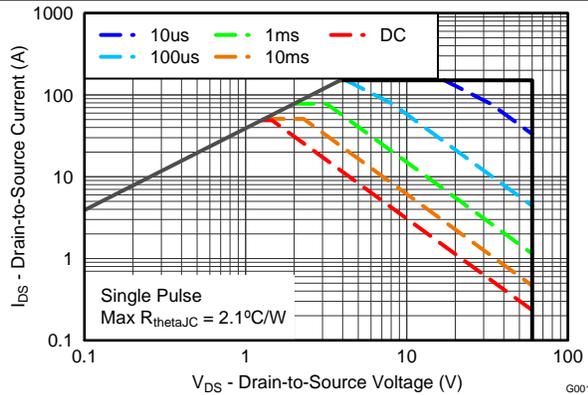


Figure 10. Maximum Safe Operating Area

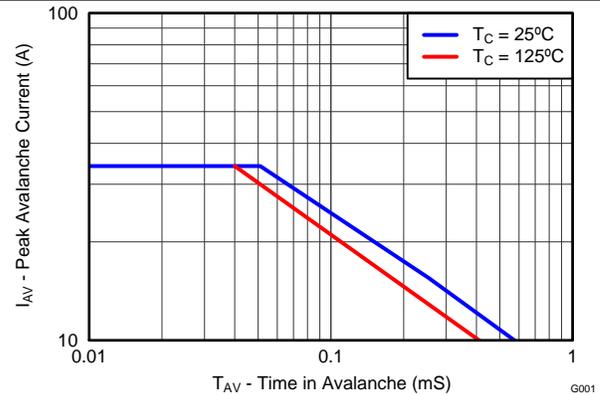


Figure 11. Single Pulse Unclamped Inductive Switching

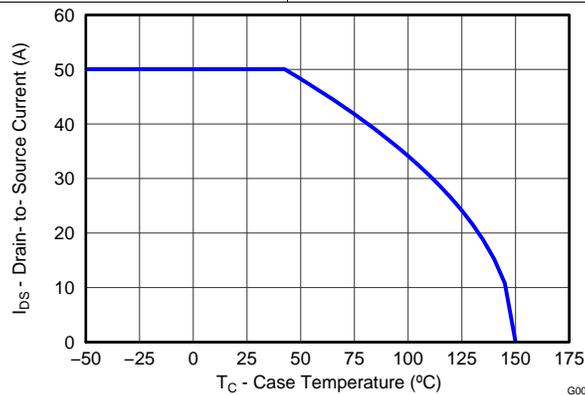


Figure 12. Maximum Drain Current vs Temperature

6 器件和文档支持

6.1 Trademarks

NexFET is a trademark of Texas Instruments.

6.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

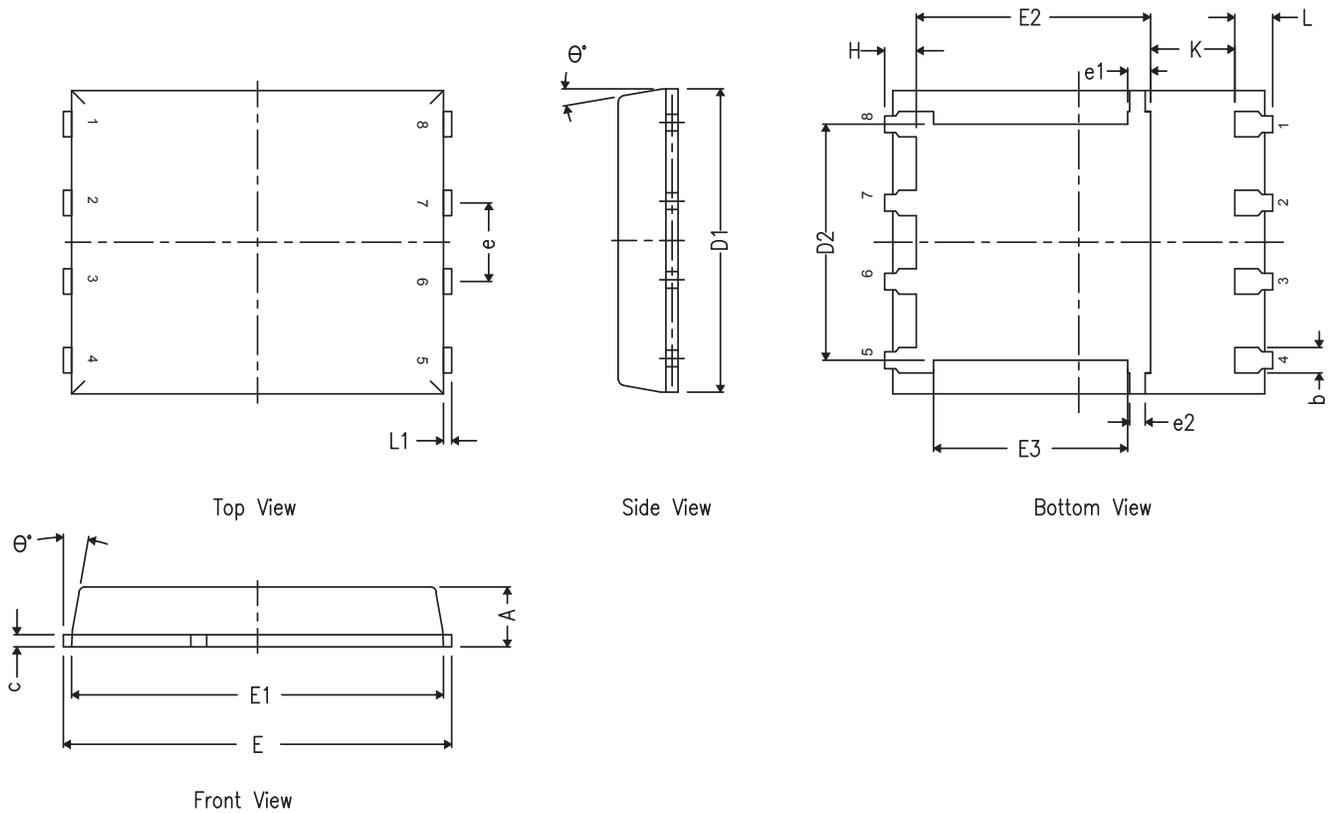
6.3 术语表

[SLYZ022](#) — *TI* 术语表。

这份术语表列出并解释术语、首字母缩略词和定义。

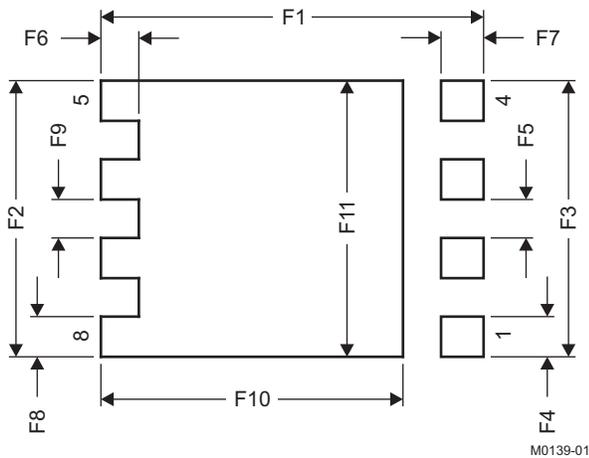
7 机械封装和可订购信息

以下页中包括机械封装和可订购信息。 这些信息是针对指定器件可提供的最新数据。 这些数据会在无通知且不对本文档进行修订的情况下发生改变。 欲获得该数据表的浏览器版本，请查阅左侧的导航栏。

7.1 Q5A 封装尺寸


DIM	毫米		
	最小值	标称值	最大值
A	0.90	1.00	1.10
b	0.33	0.41	0.51
c	0.20	0.25	0.34
D1	4.80	4.90	5.00
D2	3.61	3.81	4.02
E	5.90	6.00	6.10
E1	5.70	5.75	5.80
E2	3.38	3.58	3.78
E3	3.03	3.13	3.23
e	1.17	1.27	1.37
e1	0.27	0.37	0.47
e2	0.15	0.25	0.35
H	0.41	0.56	0.71
K	1.10	—	—
L	0.51	0.61	0.71
L1	0.06	0.13	0.20
θ	0°	—	12°

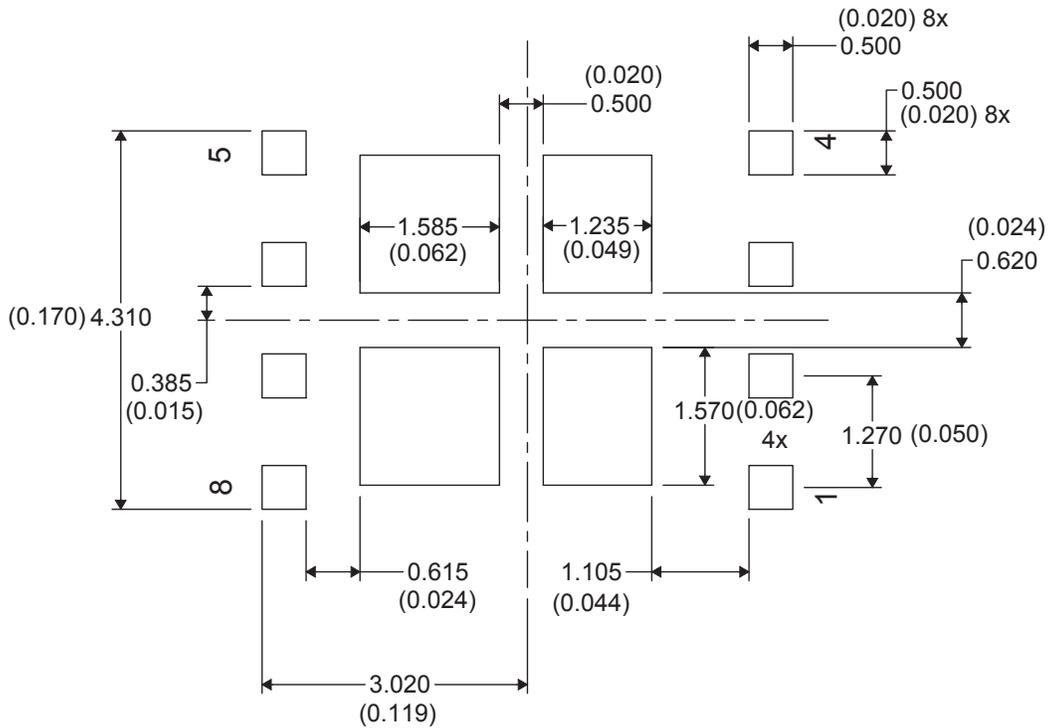
7.2 建议印刷电路板 (PCB) 布局



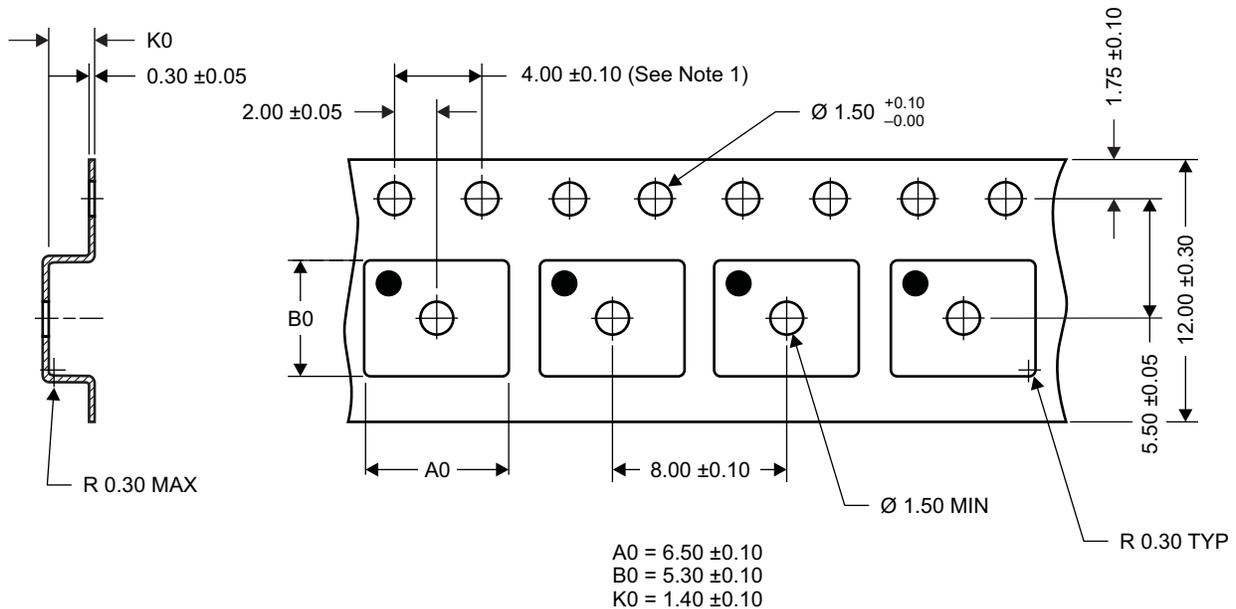
DIM	毫米		英寸	
	最小值	最大值	最小值	最大值
F1	6.205	6.305	0.244	0.248
F2	4.46	4.56	0.176	0.18
F3	4.46	4.56	0.176	0.18
F4	0.65	0.7	0.026	0.028
F5	0.62	0.67	0.024	0.026
F6	0.63	0.68	0.025	0.027
F7	0.7	0.8	0.028	0.031
F8	0.65	0.7	0.026	0.028
F9	0.62	0.67	0.024	0.026
F10	4.9	5	0.193	0.197
F11	4.46	4.56	0.176	0.18

要获得与印刷电路板 (PCB) 设计相关的建议电路布局布线, 请参见《应用说明》[SLPA005 - 通过 PCB 布局布线技巧来减少振铃](#)。

7.3 建议模板开口



7.4 Q5A 卷带信息



M0138-01

谨记:

1. 10 个链齿孔的累积容差为 ± 0.2
2. 每 100mm 长度的翘曲不能超过 1mm，在 250mm 长度上不累积
3. 材料：黑色抗静电聚苯乙烯
4. 全部尺寸单位为 mm（除非另外注明）。
5. 高于孔眼底部 0.3mm 的平面上测得的 A0 和 B0。

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
CSD18537NQ5A	Active	Production	VSONP (DQJ) 8	2500 LARGE T&R	ROHS Exempt	SN	Level-1-260C-UNLIM	-55 to 150	18537N
CSD18537NQ5A.B	Active	Production	VSONP (DQJ) 8	2500 LARGE T&R	ROHS Exempt	SN	Level-1-260C-UNLIM	-55 to 150	18537N
CSD18537NQ5AT	Active	Production	VSONP (DQJ) 8	250 SMALL T&R	ROHS Exempt	SN	Level-1-260C-UNLIM	-55 to 150	18537N
CSD18537NQ5AT.B	Active	Production	VSONP (DQJ) 8	250 SMALL T&R	ROHS Exempt	SN	Level-1-260C-UNLIM	-55 to 150	18537N

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

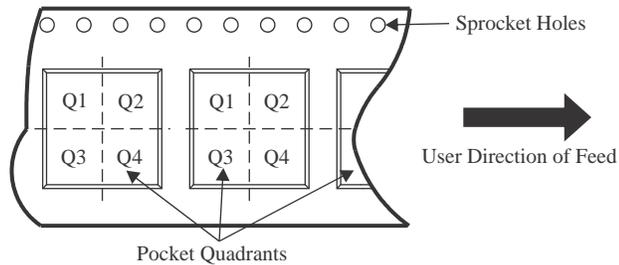
(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CSD18537NQ5A	VSONP	DQJ	8	2500	330.0	12.4	6.3	5.3	1.2	8.0	12.0	Q1
CSD18537NQ5AT	VSONP	DQJ	8	250	180.0	12.4	6.3	5.3	1.2	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

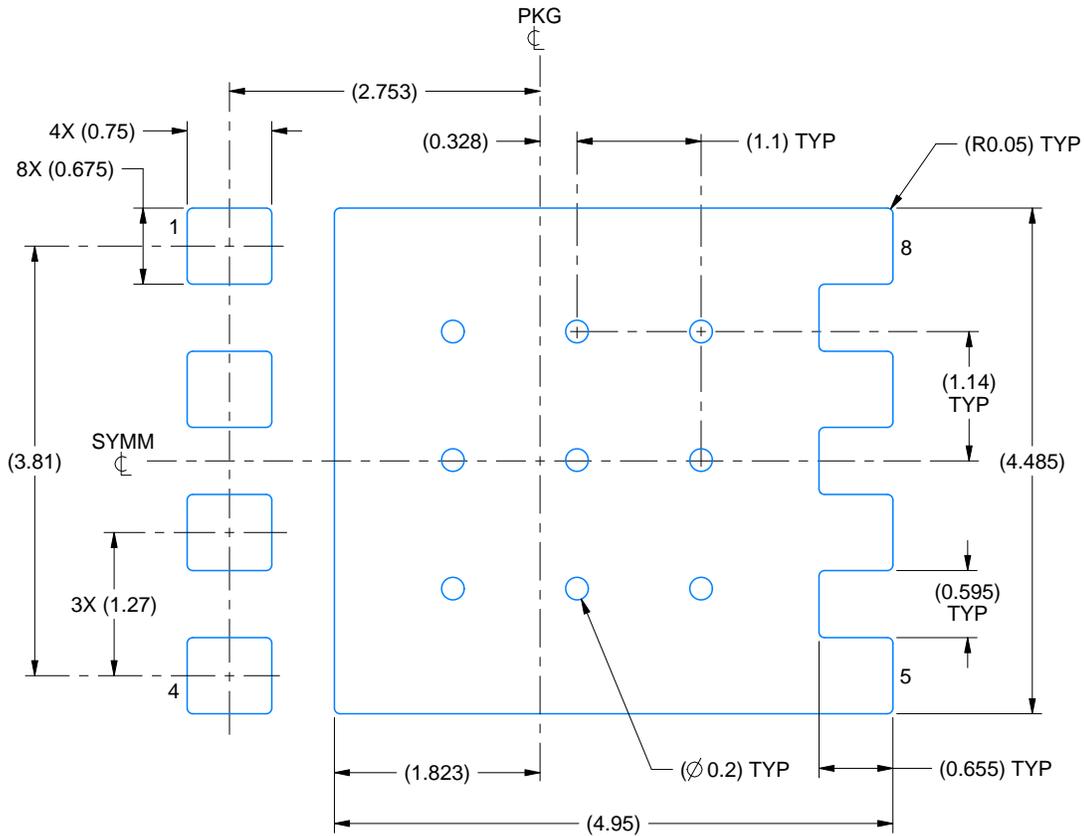
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CSD18537NQ5A	VSONP	DQJ	8	2500	340.0	340.0	38.0
CSD18537NQ5AT	VSONP	DQJ	8	250	190.0	190.0	30.0

EXAMPLE BOARD LAYOUT

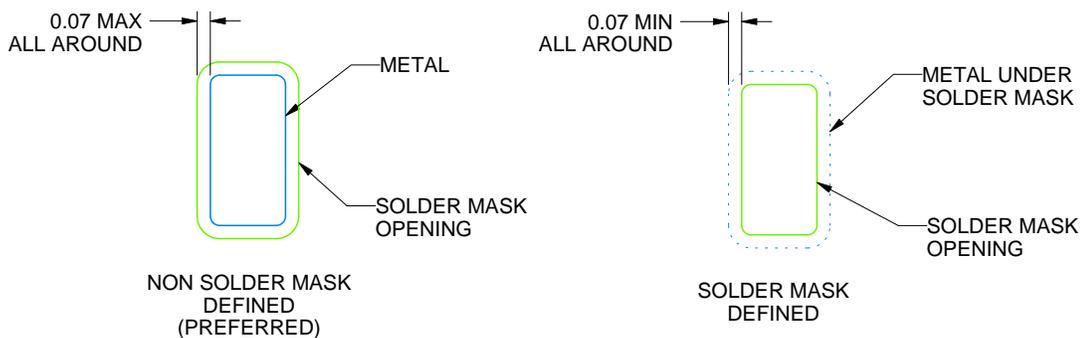
DQJ0008A

VSONP - 1.1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE
SOLDER MASK DEFINED
SCALE: 15X



SOLDER MASK DETAILS

4218866/C 02/2025

NOTES: (continued)

7. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
8. Vias are optional depending on application, refer to device data sheet. If some or all are implemented, recommended via locations are shown.

重要通知和免责声明

TI“按原样”提供技术和可靠性数据（包括数据表）、设计资源（包括参考设计）、应用或其他设计建议、网络工具、安全信息和其他资源，不保证没有瑕疵且不做任何明示或暗示的担保，包括但不限于对适销性、与某特定用途的适用性或不侵犯任何第三方知识产权的暗示担保。

这些资源可供使用 TI 产品进行设计的熟练开发人员使用。您将自行承担以下全部责任：(1) 针对您的应用选择合适的 TI 产品，(2) 设计、验证并测试您的应用，(3) 确保您的应用满足相应标准以及任何其他安全、安保法规或其他要求。

这些资源如有变更，恕不另行通知。TI 授权您仅可将这些资源用于研发本资源所述的 TI 产品的相关应用。严禁以其他方式对这些资源进行复制或展示。您无权使用任何其他 TI 知识产权或任何第三方知识产权。对于因您对这些资源的使用而对 TI 及其代表造成的任何索赔、损害、成本、损失和债务，您将全额赔偿，TI 对此概不负责。

TI 提供的产品受 [TI 销售条款](#)、[TI 通用质量指南](#) 或 [ti.com](#) 上其他适用条款或 TI 产品随附的其他适用条款的约束。TI 提供这些资源并不会扩展或以其他方式更改 TI 针对 TI 产品发布的适用的担保或担保免责声明。除非德州仪器 (TI) 明确将某产品指定为定制产品或客户特定产品，否则其产品均为按确定价格收入目录的标准通用器件。

TI 反对并拒绝您可能提出的任何其他或不同的条款。

版权所有 © 2026，德州仪器 (TI) 公司

最后更新日期：2025 年 10 月